UNISONIC TECHNOLOGIES CO., LTD

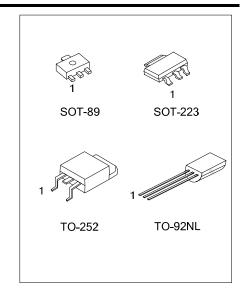
2SA1797

PNP SILICON TRANSISTOR

POWER TRANSISTOR

FEATURES

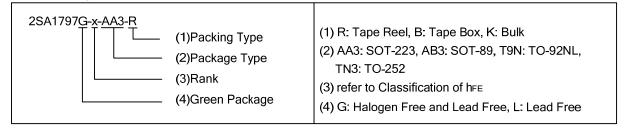
- * Low Saturation Voltage. $V_{CE(SAT)}$ =-0.35V(MAX) at I_C / I_B =-1A / -50mA
- * Excellent DC Current Gain Characteristics



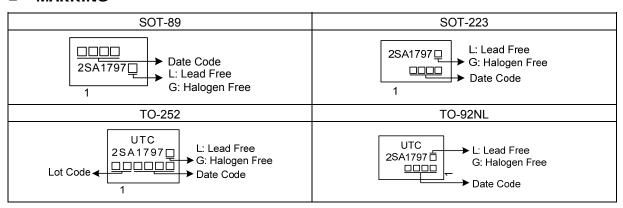
ORDERING INFORMATION

| Ordering Number | | Dookogo | Pin Assignment | | | Dooking | |
|------------------|------------------|---------|----------------|---|---|-----------|--|
| Lead Free | Halogen Free | Package | 1 | 2 | 3 | Packing | |
| 2SA1797L-x-AA3-R | 2SA1797G-x-AA3-R | SOT-223 | В | O | E | Tape Reel | |
| 2SA1797L-x-AB3-R | 2SA1797G-x-AB3-R | SOT-89 | В | O | E | Tape Reel | |
| 2SA1797L-x-T9N-B | 2SA1797G-x-T9N-B | TO-92NL | Е | O | В | Tape Box | |
| 2SA1797L-x-T9N-K | 2SA1797G-x-T9N-K | TO-92NL | Е | O | В | Bulk | |
| 2SA1797L-x-TN3-R | 2SA1797G-x-TN3-R | TO-252 | В | С | E | Tape Reel | |

Note: Pin Assignment: B: Base C: Collector E: Emitter



MARKING



www.unisonic.com.tw 1 of 4

■ **ABSOLUTE MAXIMUM RATINGS** (T_A=25°C, unless otherwise specified)

| PARAMETER | | SYMBOL | RATINGS | UNIT |
|-----------------------------|---------------|------------------|--------------|------|
| Collector-Base Voltage | | V_{CBO} | -50 | V |
| Collector-Emitter Voltage | | $V_{\sf CEO}$ | -50 | V |
| Emitter-Base Voltage | | V_{EBO} | -6 | V |
| Collector Current | DC | l _C | -2 | Α |
| | PULSE(Note 2) | | -5 | Α |
| Collector Power Dissipation | TO-92NL | P _C | 0.6 | W |
| | SOT-223 | | 0.8 (Note 3) | W |
| | SOT-89 | | 0.9 (Note 3) | W |
| | TO-252 | | 1.9 (Note 3) | W |
| Junction Temperature | | T_J | +150 | °C |
| Storage Temperature | | T _{STG} | -55 ~ +150 | °C |

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

- 2. Single pulse, P_W=10ms.
- 3. Device mounted on FR-4 PCB with minimum recommended pad layout.

■ **ELECTRICAL CHARACTERISTICS** (T_A=25°C, unless otherwise specified)

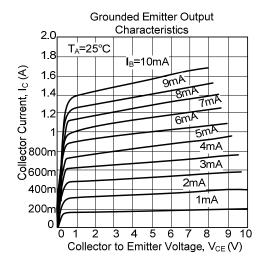
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|--------------------------------------|----------------------|--|-----|-------|-------|------|
| Collector-Base Breakdown Voltage | BV _{CBO} | $I_{C} = -50 \mu A$ | -50 | | | V |
| Collector-Emitter Breakdown Voltage | BV _{CEO} | $I_C = -1mA$ | -50 | | | V |
| Emitter-Base Breakdown Voltage | BV_{EBO} | $I_E = -50 \mu A$ | -6 | | | V |
| Collector Cutoff Current | I _{CBO} | V _{CB} = -50V | | | -0.1 | μΑ |
| Emitter Cutoff Current | I _{EBO} | V _{EB} = -5V | | | -0.1 | μΑ |
| Collector-Emitter Saturation Voltage | V _{CE(SAT)} | $I_C/I_B = -1A/-50mA$ (Note) | | -0.15 | -0.35 | V |
| DC Current Gain | h _{FE} | $V_{CE} = -2V, I_{C} = -0.5A$ (Note) | 120 | | 400 | |
| Transition Frequency | f_T | $V_{CE} = -2V$, $I_E = 0.5A$, $f = 100MHz$ | | 200 | | MHz |
| Output Capacitance | Сов | $V_{CB} = -10V, I_{E} = 0A, f = 1MHz$ | | 36 | | pF |

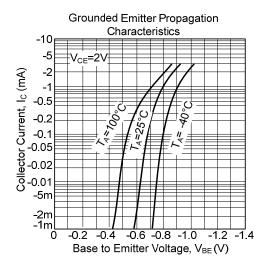
Note: Measured using pulse current.

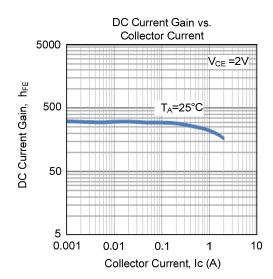
■ CLASSIFICATION OF h_{FE}

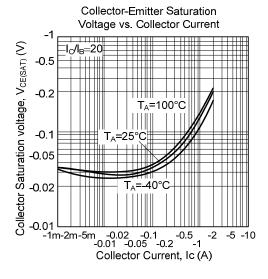
| RANK | А | В |
|-------|---------|---------|
| RANGE | 120-240 | 200-400 |

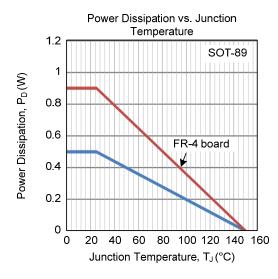
■ TYPICAL CHARACTERISTICS

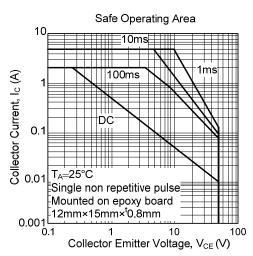












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